SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999

Optimized for Off-Line and dc-to-dc D PACKAGE (TOP VIEW) **Converters** Low Start-Up Current (<1 mA) СОМРП 14 REF **Automatic Feed-Forward Compensation** NCI 2 13 NC Pulse-by-Pulse Current Limiting VFB[]3 12 VCC NC 4 0 vC **Enhanced Load-Response Characteristics** 11 ISENSE 5 **Undervoltage Lockout With Hysteresis** NC[6 9 GND **Double-Pulse Suppression** RT/CT 8 POWER GROUND **High-Current Totem-Pole Output** Internally Trimmed Bandgap Reference NC - No internal connection 500-kHz Operation **D-8 OR P PACKAGE Error Amplifier With Low Output** (TOP VIEW) Resistance СОМР П **REF Designed to Be Interchangeable With** 8 VFB [UC2842 and UC3842 Series 7 Vcc RT/CT] OUTPUT 3 6 5 GND Δ

description

The TL284x and TL384x series of control integrated circuits provide the features that are

necessary to implement off-line or dc-to-dc fixed-frequency current-mode control schemes with a minimum number of external components. Some of the internally implemented circuits are an undervoltage lockout (UVLO), featuring a start-up current of less than 1 mA, and a precision reference trimmed for accuracy at the error amplifier input. Other internal circuits include logic to ensure latched operation, a pulse-width modulation (PWM) comparator (which also provides current-limit control), and a totem-pole output stage designed to source or sink high-peak current. The output stage, suitable for driving N-channel MOSFETs, is low when it is in the off state.

Major differences between members of these series are the UVLO thresholds and maximum duty-cvcle ranges. Typical UVLO thresholds of 16 V (on) and 10 V (off) on the TLx842 and TLx844 devices make them ideally suited to off-line applications. The corresponding typical thresholds for the TLx843 and TLx845 devices are 8.4 V (on) and 7.6 V (off). The TLx842 and TLx843 devices can operate to duty cycles approaching 100%. A duty-cycle range of 0 to 50% is obtained by the TLx844 and TLx845 by the addition of an internal toggle flip-flop, which blanks the output off every other clock cycle.

The TL284x-series devices are characterized for operation from -40°C to 85°C. The TL384x-series devices are characterized for operation from 0°C to 70°C.



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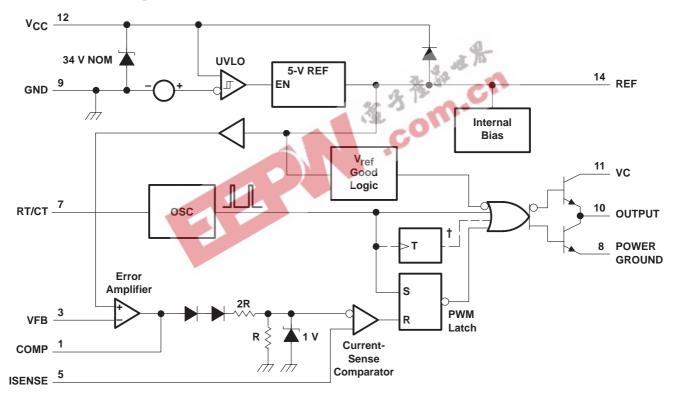
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SLVS038E – JANUARY 1989 – REVISED DECEMBER 1999

AVAILABLE OPTIONS								
	PA	CKAGED DEVICES		CHIP FORM				
TA	SMALL OUTLINE (D)	SMALL OUTLINE (D-8)	PLASTIC DIP (P)	(Y)				
0°C to 70°C	TL3842D TL3843D TL3844D TL3845D	TL3842D-8 TL3843D-8 TL3844D-8 TL3845D-8	TL3842P TL3843P TL3844P TL3845P	TL3842Y TL3843Y TL3844Y TL3845Y				
–40°C to 85°C	TL2842D TL2843D TL2844D TL2845D	TL2842D-8 TL2843D-8 TL2844D-8 TL2845D-8	TL2842P TL2843P TL2844P TL2845P	- - - -				

The D and D-8 packages are available taped and reeled. Add the suffix R to the device type (i.e., TL3842DR or TL3842DR-8). Chip forms are tested at 25°C.

functional block diagram



 † The toggle flip-flop is present only in TL2844, TL2845, TL3844, and TL3845. Pin numbers shown are for the D Package.



SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage (see Note 1) (I _{CC} < 30 mA)		Self limiting
Analog input voltage range, VI (VFB and ISENSE)		
Output voltage, V _O (OUTPUT)		
Input voltage, V _I , (VC, D package only)		
Supply current, I _{CC}		
Output current, I _O		
Error amplifier output sink current		10 mA
Package thermal impedance, θ_{JA} (see Notes 2 and 3)): D package	
	D-8 package	
	P package	
Virtual junction temperature range, T _{.1}		
Output energy (capacitive load)		
Lead temperature, 1,6 mm (1/16 inch) from case for 1		
Storage temperature range, T _{stg}		$\dots -65^{\circ}$ to 150°

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to the device GND terminal.

- All Voltages are with respect to the device GND terminal.
 Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can impact reliability.
 The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC} and VC [‡]				30	V
Input voltage, VI, RT/CT		0		5.5	V
Input voltage, VI, VFB and ISENSE		0		5.5	V
Output voltage, V _O , OUTPUT		0		30	V
Output voltage, V _O , POWER GROUND [‡]		-0.1		1	V
Supply current, externally limited, ICC				25	mA
Average output current, IO				200	mA
Reference output current, IO(ref)				-20	mA
Oscillator frequency, f _{OSC}			100	500	kHz
Operating virtual junction temperature, TJ		0		125	°C
Or arcting free air temperature T.	TL284x	-40		85	<u>^</u>
Operating free-air temperature, T _A	TL384x	0		70	°C

[‡] These recommended voltages for V_C and POWER GROUND apply only to the D package.



SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 15 V (see Note 4), $R_T = 10 \text{ k}\Omega$, $C_T = 3.3 \text{ nF}$ (unless otherwise specified)

reference section

PARAMETER	TEST CO	NDITIONS		TL284x			TL384x		UNIT
PARAMETER		INDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
Output voltage	I _O = 1 mA,	$T_A = 25^{\circ}C$	4.95	5	5.05	4.9	5	5.1	V
Line regulation	V_{CC} = 12 V to 25 V			6	20		6	20	mV
Load regulation	$I_{O} = 1 \text{ mA to } 20 \text{ mA}$			6	25		6	25	mV
Temperature coefficient of output voltage				0.2	0.4		0.2	0.4	mV/°C
Output voltage with worst-case variation	$V_{CC} = 12 V \text{ to } 25 V,$	I_{O} = 1 mA to 20 mA	4.9		5.1	4.82		5.18	V
Output noise voltage	f = 10 Hz to 10 kHz,	T _A = 25°C		50			50		μV
Output-voltage long-term drift	After 1000 h at $T_A = 2$	25°C		5	25		5	25	mV
Short-circuit output current			-30	-100	-180	-30	-100	-180	mA

[†] All typical values are at $T_A = 25^{\circ}C$.

oscillator section

NOTE 4: Adjust V_{CC} above the start threshol	TE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.				8-				
oscillator section			28.	2.2.33	10				
PARAMETER	TEST CONDITIONS		23	TL284x	0		TL384x		UNIT
FARAMETER	TEST CONDITIONS	X	MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNIT
Oscillator frequency (see Note 5)	T _A = 25°C	1.200	47	52	57	47	52	57	kHz
Frequency change with supply voltage	V _{CC} = 12 V to 25 V		0	2	10		2	10	Hz/kHz
Frequency change with temperature				50			50		Hz/kHz
Peak-to-peak amplitude at RT/CT				1.7			1.7		V

[†] All typical values are at $T_A = 25^{\circ}C$.

NOTES: 4. Adjust V_{CC} above the start threshold before setting it to 15 V.

5. Output frequency equals oscillator frequency for the TLx842 and TLx843. Output frequency is one-half oscillator frequency for the TLx844 and TLx845.

error-amplifier section

PARAMETER	TEOT	CONDITIONS		TL284x			TL384x		UNIT
PARAMETER	IESI	CONDITIONS	MIN	түр†	MAX	MIN	TYP†	MAX	UNIT
Feedback input voltage	COMP at 2.5 V		2.45	2.50	2.55	2.42	2.50	2.58	V
Input bias current				-0.3	-1		-0.3	-2	μA
Open-loop voltage amplification	$V_{O} = 2 V \text{ to } 4 V$		65	90		65	90		dB
Gain-bandwidth product			0.7	1		0.7	1		MHz
Supply-voltage rejection ratio	$V_{CC} = 12 \text{ V to } 2$	25 V	60	70		60	70		dB
Output sink current	VFB at 2.7 V,	COMP at 1.1 V	2	6		2	6		mA
Output source current	VFB at 2.3 V,	COMP at 5 V	-0.5	-0.8		-0.5	-0.8		mA
High-level output voltage	VFB at 2.3 V,	$R_L = 15 \text{ k}\Omega \text{ to GND}$	5	6		5	6		V
Low-level output voltage	VFB at 2.7 V,	$R_L = 15 \text{ k}\Omega \text{ to GND}$		0.7	1.1		0.7	1.1	V

[†] All typical values are at $T_A = 25^{\circ}C$.

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.



SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 15 V (see Note 4), R_T = 10 k Ω , C_T = 3.3 nF (unless otherwise specified) (continued)

current-sense section

PARAMETER	TEST CONDITIONS		TL284x			TL384x			UNIT
PARAMETER	TESTCOND	TIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
Voltage amplification	See Notes 6 and 7		2.85	3	3.13	2.85	3	3.15	V/V
Current-sense comparator threshold	COMP at 5 V,	See Note 6	0.9	1	1.1	0.9	1	1.1	V
Supply-voltage rejection ratio	$V_{CC} = 12 \text{ V to } 25 \text{ V},$	See Note 6		70			70		dB
Input bias current				-2	-10		-2	-10	μA
Delay time to output				150	300		150	300	ns

[†] All typical values are at $T_A = 25^{\circ}C$.

NOTES: 4. Adjust V_{CC} above the start threshold before setting it to 15 V.

6. These parameters are measured at the trip point of the latch, with VFB at 0 V.

7. Voltage amplification is measured between ISENSE and COMP, with the input changing from 0 V to 0.8 V.

output section

PARAMETER TEST CONDITIONS		TL384x	UNIT
TEST CONDITIONS	MIN TYPT MAX	ΜΙΝ ΤΥΡ [†] ΜΑΧ	UNIT
$I_{OH} = -20 \text{ mA}$	13 13.5	13 13.5	V
I _{OH} = -200 mA	12 13.5	12 13.5	v
I _{OL} = 20 mA	0.1 0.4	0.1 0.4	V
I _{OL} = 200 mA	1.5 2.2	1.5 2.2	v
$C_L = 1 \text{ nF}, T_A = 25^{\circ}C$	50 150	50 150	ns
$C_L = 1 \text{ nF}, \qquad T_A = 25^{\circ}C$	50 150	50 150	ns
	$I_{OH} = -20 \text{ mA}$ $I_{OH} = -200 \text{ mA}$ $I_{OL} = 20 \text{ mA}$ $I_{OL} = 200 \text{ mA}$ $C_L = 1 \text{ nF}, \qquad T_A = 25^{\circ}\text{C}$	MIN TYPT MAX $I_{OH} = -20 \text{ mA}$ 13 13.5 $I_{OH} = -200 \text{ mA}$ 12 13.5 $I_{OL} = 20 \text{ mA}$ 0.1 0.4 $I_{OL} = 200 \text{ mA}$ 1.5 2.2 $C_L = 1 \text{ nF}$, $T_A = 25^{\circ}C$ 50 150	TEST CONDITIONSMINTYPIMAXMINTYPIMAX $I_{OH} = -20 \text{ mA}$ 1313.51313.5 $I_{OH} = -200 \text{ mA}$ 1213.51213.5 $I_{OH} = -200 \text{ mA}$ 1213.51213.5 $I_{OL} = 20 \text{ mA}$ 0.10.40.10.4 $I_{OL} = 200 \text{ mA}$ 1.52.21.52.2 $C_L = 1 \text{ nF},$ $T_A = 25^{\circ}C$ 5015050150

[†] All typical values are at $T_A = 25^{\circ}C$.

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

undervoltage-lockout section

DADAMETED	PARAMETER		TL284x			TL384x		
PARAMETER		MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
Start threshold voltage	TLx842, TLx844	15	16	17	14.5	16	17.5	V
	TLx843, TLx845	7.8	8.4	9	7.8	8.4	9	v
Minimum operating voltage after startup	TLx842, TLx844	9	10	11	8.5	10	11.5	V
Minimum operating voltage after startup	TLx843, TLx845	7	7.6	8.2	7	7.6	8.2	v

[†] All typical values are at $T_A = 25^{\circ}C$.

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

pulse-width-modulator section

DADAMETED	PARAMETER		TL284x			TL384x		
PARAMEIER		MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
Maximum duty cycle	TLx842, TLx843	95%	97%	100%	95%	97%	100%	
	TLx844, TLx845	46%	48%	50%	46%	48%	50%	
Minimum duty cycle				0			0	

[†] All typical values are at $T_A = 25^{\circ}C$.

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.



SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 15 V (see Note 4), R_T = 10 k Ω , C_T = 3.3 nF (unless otherwise specified) (continued)

supply voltage

PARAMETER	TEST CONDITIONS	TL284x			TL384x			UNIT
PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT
Start-up current			0.5	1		0.5	1	mA
Operating supply current	VFB and ISENSE at 0 V		11	17		11	17	mA
Limiting voltage	I _{CC} = 25 mA		34			34		V

[†] All typical values are at $T_A = 25^{\circ}C$.

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

electrical characteristics, V_{CC} = 15 V (see Note 4), R_T = 10 k Ω , C_T = 3.3 nF, T_A = 25°C (unless otherwise specified)

reference section

PARAMETER	TEST CONDITIONS	TL384xY	UNIT
PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
Output voltage	I _O = 1 mA	5	V
Line regulation	V _{CC} = 12 V to 25 V	6	mV
Load regulation	IO = 1 mA to 20 mA	6	mV
Temperature coefficient of output voltage		0.2	mV/°C
Output noise voltage	f = 10 Hz to 10 kHz	50	μV
Output-voltage long-term drift	Af <mark>ter 1000 h a</mark> t T _A = 25°C	5	mV
Short-circuit output current		-100	mA

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

oscillator section

PARAMETER	TEST CONDITIONS	TI	UNIT		
PARAMETER		MIN	TYP	MAX	UNIT
Oscillator frequency (see Note 5)			52		kHz
Frequency change with supply voltage	$V_{CC} = 12 \text{ V to } 25 \text{ V}$		2		Hz/kHz
Frequency change with temperature			5		Hz/kHz
Peak-to-peak amplitude at RT/CT			1.7		V

NOTES: 4. Adjust V_{CC} above the start threshold before setting it to 15 V.

5. Output frequency equals oscillator frequency for the TLx842 and TLx843. Output frequency is one-half oscillator frequency for the TLx844 and TLx845.



SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999

electrical characteristics, V_{CC} = 15 V (see Note 4), R_T = 10 k Ω , C_T = 3.3 nF, T_A = 25°C (unless otherwise specified) (continued)

error-amplifier section

PARAMETER	те	TEST CONDITIONS		TL384xY			
PARAMETER	PARAMETER		MIN	TYP	MAX	UNIT	
Feedback input voltage	COMP at 2.5 V			2.50		V	
Input bias current				-0.3		μA	
Open-loop voltage amplification	$V_0 = 2 V \text{ to } 4 V$			90		dB	
Gain-bandwidth product				1		MHz	
Supply-voltage rejection ratio	V _{CC} = 12 V to 25	V		70		dB	
Output sink current	VFB at 2.7 V,	COMP at 1.1 V		6		mA	
Output source current	VFB at 2.3 V,	COMP at 5 V		-0.8		mA	
High-level output voltage	VFB at 2.3 V,	$R_L = 15 \text{ k}\Omega \text{ to GND}$		6		V	
Low-level output voltage	VFB at 2.7 V,	$R_L = 15 \text{ k}\Omega \text{ to GND}$		0.7		V	

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

current-sense section

PARAMETER	TEST CONDITIONS	TL384xY			
	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Voltage amplification	See Notes 6 and 7		3		V/V
Current-sense comparator threshold	COMP at 5 V, See Note 6		1		V
Supply-voltage rejection ratio	V _{CC} = 12 V to 25 V, See Note 6		70		dB
Input bias current			-2		μΑ
Delay time to output			150		ns

£....

NOTES: 4. Adjust V_{CC} above the start threshold before setting it to 15 V.

6. These parameters are measured at the trip point of the latch, with VFB at 0 V.

7. Voltage amplification is measured between ISENSE and COMP, with the input changing from 0 V to 0.8 V.

output section

PARAMETER	TEST CONDITIONS	T	UNIT				
	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
High-level output voltage	$I_{OH} = -20 \text{ mA}$		13.5				
	I _{OH} = -200 mA		13.5		V		
Low-level output voltage	I _{OL} = 20 mA		0.1		V		
	I _{OL} = 200 mA		1.5		v		
Rise time	C _L = 1 nF		50		ns		
Fall time	C _L = 1 nF		50		ns		

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

undervoltage-lockout section

PARAMETER		TL384xY			UNIT
		MIN	TYP	MAX	UNIT
Start threshold voltage	TL3842Y, TL3844Y		16		V
	TL3843Y, TL3845Y		8.4		v
Minimum operating voltage after startup	TL3842Y, TL3844Y		10		V
	TL3843Y, TL3845Y		7.6		v

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999

electrical characteristics, V_{CC} = 15 V (see Note 4), R_T = 10 k Ω , C_T = 3.3 nF, T_A = 25°C (unless otherwise specified) (continued)

pulse-width-modulator section

PARAMETER		т	UNIT		
		MIN	TYP	MAX	
	TL3842Y, TL3843Y		97%		
Maximum duty cycle	TL3844Y, TL3845Y		48%		

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.

supply voltage

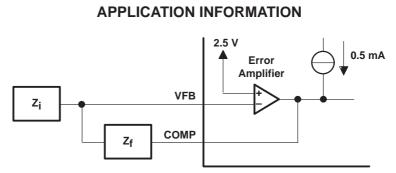
PARAMETER	TEST CONDITIONS	TL384xY			UNIT
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Start-up current			0.5	1	mA
Operating supply current	VFB and ISENSE at 0 V		11	17	mA
Limiting voltage	I _{CC} = 25 mA		34		V

NOTE 4: Adjust V_{CC} above the start threshold before setting it to 15 V.



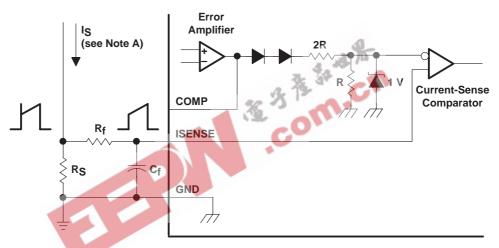


SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999



NOTE A: Error amplifier can source or sink up to 0.5 mA.



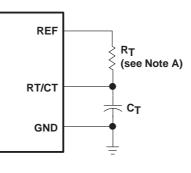


NOTE A: Peak current (IS) is determined by the formula:

$$I_{S(max)} = \frac{1 V}{R}$$

A small RC filter formed by resistor R_f and capacitor C_f may be required to suppress switch transients.

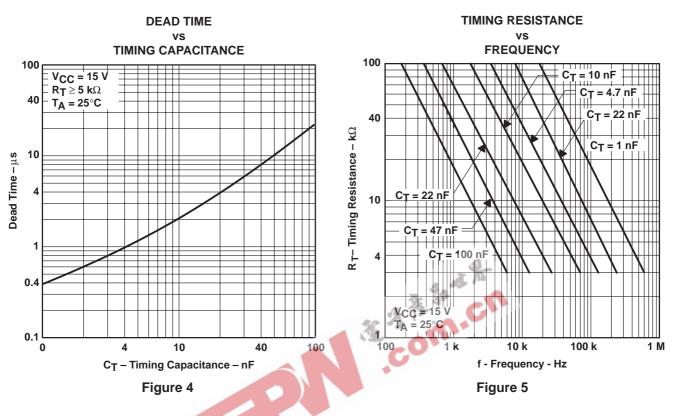
Figure 2. Current-Sense Circuit



NOTE A: For $R_T > 5 \text{ k}\Omega$: $f \approx \frac{1.72}{R_T C_T}$

Figure 3. Oscillator Section

SLVS038E - JANUARY 1989 - REVISED DECEMBER 1999



APPLICATION INFORMATION

open-loop laboratory test fixture

In the open-loop laboratory test fixture shown in Figure 6, high peak currents associated with loads necessitate careful grounding techniques. Timing and bypass capacitors should be connected close to the GND terminal in a single-point ground. The transistor and 5-k Ω potentiometer sample the oscillator waveform and apply an adjustable ramp to the ISENSE terminal.

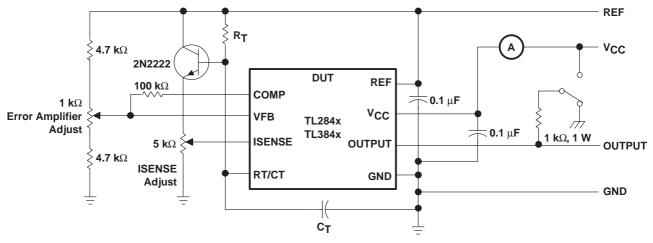


Figure 6. Open-Loop Laboratory Test Fixture

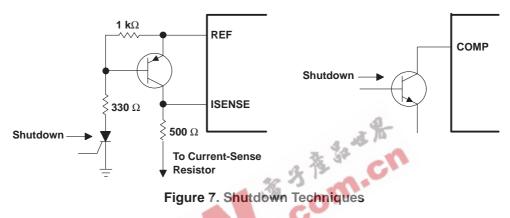


SLVS038E – JANUARY 1989 – REVISED DECEMBER 1999

APPLICATION INFORMATION

shutdown technique

The PWM controller (see Figure 7) can be shut down by two methods: either raise the voltage at ISENSE above 1 V or pull the COMP terminal below a voltage two diode drops above ground. Either method causes the output of the PWM comparator to be high (refer to block diagram). The PWM latch is reset dominant so that the output remains low until the next clock cycle after the shutdown condition at the COMP or ISENSE terminal is removed. In one example, an externally latched shutdown can be accomplished by adding an SCR that resets by cycling V_{CC} below the lower UVLO threshold. At this point, the reference turns off, allowing the SCR to reset.



A fraction of the oscillator ramp can be resistively summed with the current-sense signal to provide slope compensation for converters requiring duty cycles over 50% (see Figure 8). Note that capacitor C forms a filter with R2 to suppress the leading-edge switch spikes.

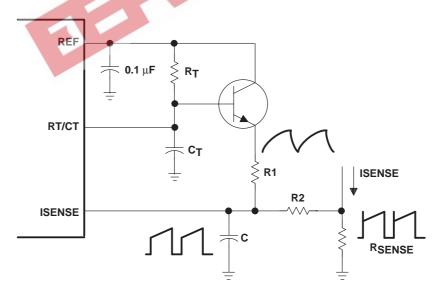


Figure 8. Slope Compensation



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